1 Scope

The present specifications shall apply to Sanken silicon diode, RM2B.

2 Outline

Туре	Silicon Diode
Structure	Resin Molded
Applications	Commercial Frequency Rectification

3 Flammability

4 Absolute maximum ratings

 3 Flammability UL94V-0(Equivalent) 4 Absolute maximum ratings 							
No	. Item	S	Symbol	Unit	Rating	Conditions	
1	Transient Peak Reverse	e Voltage	V _{RSM}	v	850		
2	Peak Reverse Voltage		V _{RM}	V	800		
3	Average Forward Curre	ent	$I_{F(AV)}$	A	1.2	Refer to derating curve in Section 7	
4	Peak Surge Forward Cu	urrent	I _{FSM}	A	100	10ms. Half sine wave, one shot	
5	I ² t Limiting Value		I ² t	A ² s	50	1ms≦i≦10ms	
6	Junction Temperature		Tj	°C	-40~+150		
7	Storage Temperature		T _{stg}	°C	-40~+150		

5 Electrical characteristics (Ta=25°C, unless otherwise specified)

No.	Item	Symbol	Unit	Rating	Conditions
1	Forward Voltage Drop	$V_{\rm F}$	v	0.91 max.	I _F =1.5A
2	Reverse Leakage Current	I _R	μΑ	10 max.	V _R =V _{RM}
3	Reverse Leakage Current Under High Temperature	H∙I _R	μΑ	50 max.	V _R =V _{RM} , T _j =100°C
4	Thermal Resistance	R _{th(j-l)}	°C/W	12 max.	Between Junction and Lead



8 Package information

8-1Package type, physical dimensions and material

